

SILICON POWER TRANSISTORS 2SA1615, 1615-Z

PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SA1615 and 1615-Z are available for the large current control in small dimension due to the low saturation and are ideal for high-efficiency DC/DC converters due to the fast switching speed.

FEATURES

· Large current capacity:

Ic(DC): -10 A, Ic(pulse): -15 A

• High hee and low collector saturation voltage:

hfe = 200 MIN. (@Vce = -2.0 V, Ic = -0.5 A)

 $V_{CE(sat)} \le -0.25 \text{ V } (@I_{C} = -4.0 \text{ A}, I_{B} = -0.05 \text{ A})$ WWW.DZSC.COM

QUALITY GRADES

Standard

Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications. WWW.DZSC.COM

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit	
Collector to base voltage	VcBO	30	٧	
Collector to emitter voltage	Vceo	-20	V	
Emitter to base voltage	VEBO	-10	٧	
Collector current (DC)	Ic(DC)	-10	Α	
Collector current (pulse)	IC(pulse)*	-15	Α	
Base current (DC)	I _{B(DC)}	-0.5	Α	
Total power dissipation	P _T (T _a = 25°C)**	1.0	W	
Total power dissipation	P _T (T _c = 25°C)	15	W	
Junction temperature	T _i	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

PW ≤ 10 ms, duty cycle ≤ 50%

^{**} Printing board mounted





ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	V _{CB} = -20 V, I _E = 0			-1.0	μΑ
Emitter cutoff current	ІЕВО	$V_{EB} = -8.0 \text{ V}, \text{ Ic} = 0$			-1.0	μΑ
DC current gain	h _{FE1} *	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}$	200		600	
DC current gain	h _{FE2} *	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -4.0 \text{ A}$	160			
Collector saturation voltage	V _{CE(sat)} *	$I_C = -4.0 \text{ A}, I_B = -0.05 \text{ A}$		-0.2	-0.25	V
Base saturation voltage	V _{BE(sat)} *	$I_C = -4.0 \text{ A}, I_B = -0.05 \text{ A}$		-0.9	-1.2	V
Gain bandwidth product	f⊤	Vce = -5.0 V, Ie = 1.5 A		180		MHz
Output capacity	Сор	V _{CB} = -10 V, I _E = 0, f = 1.0 MHz		220		pF
Turn-on time	ton	$Ic = -5.0 \text{ A}, I_{B1} = -I_{B2} = 0.125 \text{ A},$		80		ns
Storage time	tstg	$R_L = 2.0 \Omega$, $V_{CC} \cong -10 V$		300		ns
Fall time	tf			60		ns

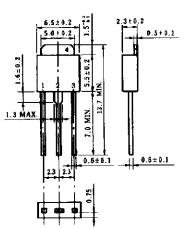
^{*} Pulse test PW \leq 350 μ s, duty cycle \leq 2%

hfe CLASSIFICATION

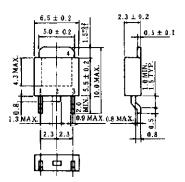
Marking	L	K
h _{FE2}	200 to 400	300 to 600

PACKAGE DRAWING (UNIT: mm)

2SA1615



2SA1615-Z

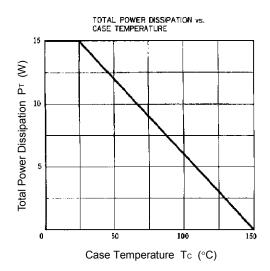


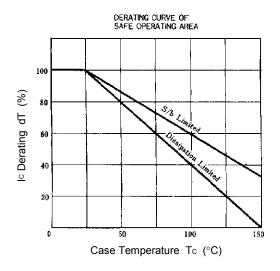
Electrode Connection

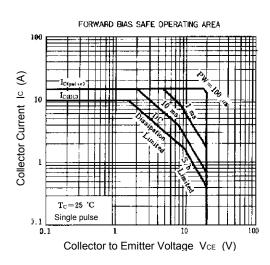
- 1. Base
- 2. Collector
- 3. Emitter
- 4. Collector (fin)

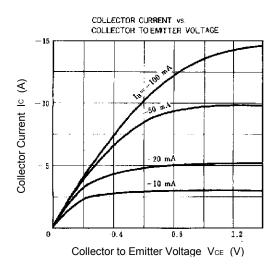
NEC

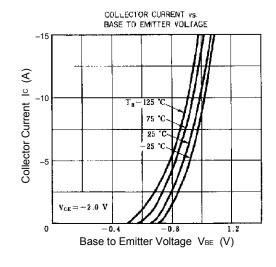
TYPICAL CHARACTERISTICS (Ta = 25 °C)

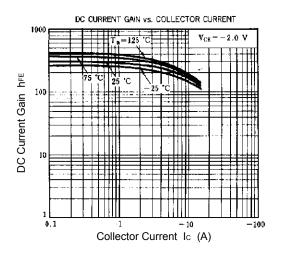


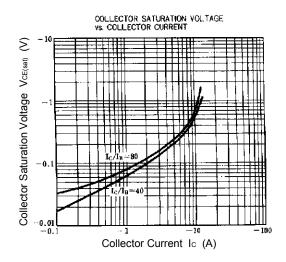


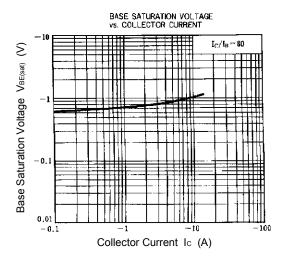




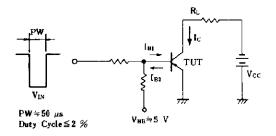


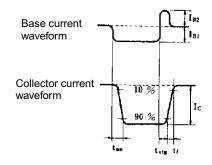






SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT







[MEMO]



- The information in this document is current as of July, 2001. The information is subject to change
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